



# **PRODUCT RELIABILITY REPORT**

**Product: MPQ2451-AEC1**

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## 1. Device Information

Product:	MPQ2451-AEC1
Package:	QFN2×2-6, SOT-6 and TSOT-6
Process Technology:	BCD
Report Date:	05/14/2019

## 2. Summary of Test Results

Test	#	Test Condition	Lot# or Date Code	Test Results (S.S./Rej)	Comment
Temperature, Bias, and Operating Life	B1	JESD22-A108, @+125°C for 1000 hours or equivalent	FA859120A FA859121B 96727857	80/0 80/0 80/0	
Early Life Failure Rate (ELFR)	B2	AEC-Q100-008, @ +125°C for 48 hours, or equivalent	FA859120A FA859121B 96727857	800/0 800/0 800/0	
ESD: Human Body Model (HBM)	E2	AEC-Q100-002	FA859120A	3/0	>2000V
ESD: Machine Model (MM)	E2	AEC-Q100-003	FA859120A	3/0	>200V
ESD: Device Charged Model (CDM)	E3	AEC-Q100-011	FA859120A	3/0	>750V
Latch-up	E4	AEC-Q100-004	FA859120A	6/0	>+/-100mA & >1.5Vccmax
Moisture/Reflow Sensitivity	A1	J-STD-020	1444 1446 1448 1222 1224 1227 1732 1734 1735	300/0 300/0 300/0 300/0 300/0 300/0 300/0 300/0 300/0	QFN2×2-6,MSL=1 QFN2×2-6,MSL=1 QFN2×2-6,MSL=1 SOT-6,MSL=1 SOT-6,MSL=1 SOT-6,MSL=1 TSOT-6,MSL=1 TSOT-6,MSL=1 TSOT-6,MSL=1
Steady State Temperature Humidity Bias Life	A2	JESD22-A101, @85°C/85%RH static bias at Vinmax for	1444 1446 1448	80/0 80/0 80/0	QFN2×2-6 QFN2×2-6 QFN2×2-6

Test		1000 hours or equivalent	1222 1224 1227 1732 1734 1735	80/0 80/0 80/0 80/0 80/0 80/0	SOT-6 SOT-6 SOT-6 TSOT-6 TSOT-6 TSOT-6
Accelerated Moisture Resistance-Unbiased Autoclave	A3	JESD22-A102, @121°C/100%RH for 168 hours or equivalent	1444 1446 1448 1222 1224 1227 1732 1734 1735	80/0 80/0 80/0 80/0 80/0 80/0 80/0 80/0 80/0	QFN2×2-6 QFN2×2-6 QFN2×2-6 SOT-6 SOT-6 SOT-6 TSOT-6 TSOT-6 TSOT-6
Temperature Cycling	A4	JESD22-A104, from -65°C to 150°C for 1000 cycles or equivalent	1444 1446 1448 1222 1224 1227 1732 1734 1735	80/0 80/0 80/0 80/0 80/0 80/0 80/0 80/0 80/0	QFN2×2-6 QFN2×2-6 QFN2×2-6 SOT-6 SOT-6 SOT-6 TSOT-6 TSOT-6 TSOT-6
Power Temperature Cycling	A5	JESD22-A105, from -40°C to 125°C for 1000 cycles.	FA757525	45/0	
High Temperature Storage Life	A6	JESD22-A103, @150°C for 1000 hours	1444 1446 1448 1222 1224 1227 1732 1734 1735	50/0 50/0 50/0 50/0 50/0 50/0 50/0 50/0 50/0	QFN2×2-6 QFN2×2-6 QFN2×2-6 SOT-6 SOT-6 SOT-6 TSOT-6 TSOT-6 TSOT-6

### **3. Failure Rate Calculation**

Sample Size:	4580
Rejects:	0
Activation Energy (eV):	0.7
Equivalent Device Hours:	$3.57 \times 10^8$ Hours
Failure Rate (FIT@60%CL):	2.6 FIT
MTBF (years):	44,569 Years

### **Revision / Update History**

<u>Revision</u>	<u>Reason for Change</u>	<u>Date</u>	<u>Rel Engineer</u>
1.0	Initial release	August 2013	Ramon Lei
2.0	Update	February 2014	Ramon Lei
3.0	Update	March 2015	Lance Liu
4.0	Update	February 2018	Ramon Lei
5.0	Update	May 2019	Ramon Lei

## **Appendix: Description of Reliability Test and Failure Rate Calculation**

### **High Temperature Operating Life Test**

**Purpose:** This test is a worst-case life test that checks the integrity of the product. The high temperature testing is use for acceleration of any potential failures over time. The calculation for failure rate (FIT) using the operating ambient temperature is done using the Arrhenius equation.

**Condition:** 125°C @ Vinmax

**Pass Criteria:** All units must pass the min/max limits of the datasheet.

### **ESD Test**

**Purpose:** The purpose of the ESD test is to guarantee that the device can withstand electrostatic voltages during handling.

**Condition:** Human Body Model, Machine Model and Charged Device Model

**Pass Criteria:** ESD Testing on every pin. The device must be fully functional after testing and pass the min/max limits in the datasheet.

### **IC Latch-Up Test**

**Purpose:** The purpose of this specification is to establish a method for determining IC latch-up characteristics and to define latch-up failure criteria. Latch-up characteristics are extremely important in determining product reliability and minimizing No Trouble Found (NTF) and Electrical Overstress (EOS) failures due to latch-up.

**Condition:** Voltage and current injection

**Pass criteria:** All pins with the exception of “no connect” pins and timing related pins, shall be latch-up tested. The device must be fully functional after testing and pass the min/max limits in the datasheet.

### **Moisture/Reflow Sensitivity Classification for Nonhermetic Solid State Surface Mount Devices**

**Purpose:** The purpose of this standard is to identify the classification level of nonhermetic solid state surface mount devices (SMDs) that are sensitive to moisture-induced stress so that they can be properly packaged, stored, and handled to avoid damage during assembly solder reflow attachment and/or repair operations.

**Condition:** Bake + moisture sock + 3X reflow at 260°C

**Pass criteria:** All units must pass the min/max limits of the datasheet

### **Accelerated Moisture Resistance- Unbiased Autoclave**

**Purpose:** To check the performance of the device in humid environments. This test checks the integrity of the passivation, poor metal to plastic seal and contamination level during assembly and material compatibility.

**Condition:** 121°C/15psig/100% RH (no bias)

**Pass Criteria:** All units must pass min/max limits of the datasheet

### **Temperature Cycle Test**

**Purpose:** This test is used to evaluate the die attach integrity and bond integrity. This is similar to the Thermal Shock test, but can generate different failure modes due to the longer dwell time and gradual temperature change.

**Condition:** -65°C to 150°C

**Pass Criteria:** All units must pass min/max limits of the datasheet

### **Steady State Temperature Humidity Bias Life Test**

**Purpose:** This is to check the performance of the device in humid environments. This test checks the integrity of the passivation, poor metal to plastic seal and contamination level during assembly and material compatibility.

**Condition:** 85%RH at 85°C with Vin=Vinmax

**Pass Criteria:** All units must pass min/max limits of the datasheet

### Highly Accelerated Temperature and Humidity Stress Test

- Purpose:** This is an equivalent test to Steady State Temperature Humidity Bias Life test with different (higher) temperature stress condition.
- Condition:** 85%RH at 130°C with Vin=Vinmax
- Pass Criteria:** All units must pass min/max limits of the datasheet

### Failure Rate Calculation

The failure rate is gauged by a Failures-In-Time (FIT) based upon accelerated stress data. The unit for FIT is failure per billion device hour.

$$FIT\ Rate = \frac{(\chi^2/2) \times 10^9}{EDH}$$

Where

- χ<sup>2</sup> (Chi-Squared) is the goodness-of-fit test statistic at a specified level of confidence;
- EDH= Equivalent Device Hours = AF × (Life test sample size) × (test duration);
- AF= Acceleration Factor.

High Temperature Operating Life (HTOL) test is usually done under acceleration of temperature and voltage. The total number of failures from the stress test determines the chi-squared factor.

$$AF = AF_T \times AF_V$$

The Temperature Acceleration Factor AF<sub>T</sub>:

$$AF_T = \exp\left(\frac{E_a}{K} \left(\frac{1}{T_{J(Use)}} - \frac{1}{T_{J(Stress)}}\right)\right)$$

- T<sub>use</sub> = Junction temp under typical operating conditions;
- T<sub>stress</sub> = Junction temp under accelerated test conditions;
- E<sub>a</sub> is Activation energy=0.7eV;
- K=Boltzmann's constant=8.62×10<sup>-5</sup> eV/K.

The voltage Acceleration Factor AF<sub>V</sub>:

$$AF_V = e^{\beta \times [V_{stress} - V_{use}]}$$

- V<sub>use</sub> = Gate voltage under typical operating conditions;
- V<sub>stress</sub> = Gate voltage under accelerated test conditions;
- β = Voltage acceleration factor (in 1/Volts) and specified by technology.
- Note: For calculation in the report, AF<sub>V</sub> = 1 for simplicity.

MTBF (Mean Time Between Failure) equals to 10<sup>9</sup>/FIT (in hours).